

# MT29F3T08EUHBBM4-3RES:B TR

#### MT29F3T08EUHBBM4-3RES:B TR Information

Contraction to the second seco	 MT29F3T08EUHBBM4-3RES:B TR Micron Technology Inc. Integrated Circuits (ICs) Memory IC FLASH 3TBIT 333MHZ 132LBGA - For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



## MT29F3T08EUHBBM4-3RES:B TR Specifications

Manufacturer Part Number	MT29F3T08EUHBBM4-3RES:B TR
Manufacturer	Micron Technology Inc.
Category	Integrated Circuits (ICs)
	Memory
Package	-
Series	-
Memory Type	Non-Volatile
Memory Format	FLASH
Technology	FLASH - NAND
Memory Size	3Tb (384G x 8)
Memory Interface	Parallel
Clock Frequency	333MHz
Write Cycle Time - Word, Page	-
Access Time	-
Voltage - Supply	2.5 V ~ 3.6 V
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	-
Package / Case	-
Supplier Device Package	-
	Report errors?

#### MT29F3T08EUHBBM4-3RES:B TR Guarantees



**Quality Guarantees** 

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

#### MT29F3T08EUHBBM4-3RES:B TR Payment Methods





If you have any question about MT29F3T08EUHBBM4-3RES:B TR, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com